## NSN 5961-01-129-0020

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-129-0020 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.107 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-7 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 reverse voltage, dc **Current Rating Per Characteristic:** 0.02 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** The voltage rating is a value iaw pn zc803 fscm 18518; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: